Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	7	(("U5-6,215,180") or ("5-5,777, 847") or ("5,650,918") or ("5,510, 956") or ("5,276,586") or ("5,285, 350") or ("4,716,396") or ("5,891, 753") or ("6,288,900")).PN.	US-PGPUB; USPAT	OR	OFF	2005/02/09 21:06
L2	37051	gate.clm. and electrode.clm.	US-PGPUB; USPAT	OR	OFF	2005/02/09 21:06
L3	27372	2 and insulat$3	US-PGPUB; USPAT	OR	OFF	2005/02/09 21:07
L4	6836	3 and (etch43 or pattern$3).clm.	US-PGPUB; USPAT	OR	OFF	2005/02/09 21:07
L5	10017	3 and (etch$3 or pattern$3).clm.	US-PGPUB; USPAT	OR	OFF	2005/02/09 21:07
L6	851	5 and ((varied or varying or vary or different) near4 (thickness or thick))	US-PGPUB; USPAT	OR	OFF	2005/02/09 21:11
L7	680	6 and ((insulat$3 or dielectric or interlayer) near8 thick$4)	US-PGPUB; USPAT	OR	OFF	2005/02/09 21:09
L8	569	7 and (second near3 (insulat$3 or gate or electrode or dielectric))	US-PGPUB; USPAT	OR	OFF	2005/02/09 21:22
L9	379	8 and ((transistor$1 and capacitor$1) or memory)	US-PGPUB; USPAT	OR	OFF	2005/02/09 21:11
L10	260	9 and ("thick$4.ab" or thick$4.clm.)	US-PGPUB; USPAT	OR	OFF	2005/02/09 21:11
L11	107	10 and (((varied or varying or vary or different) near4 (thickness or thick)).ab. or ((varied or varying or vary or different) near4 (thickness or thick)).clm.)	US-PGPUB; USPAT	OR	OFF	2005/02/09 21:12
L12	68	11 and (third near3 (insulat$3 or gate or electrode or dielectric))	US-PGPUB; USPAT	OR	OFF	2005/02/09 21:23
L13	45	12 and (third near8 thick$4)	US-PGPUB; USPAT	OR	OFF	2005/02/09 21:23